

## Product Summary

BV <sub>DSS</sub>	R <sub>DS(on)</sub> Max	I <sub>D</sub> T <sub>A</sub> = +25°C
-40V	60mΩ @ V <sub>GS</sub> = -10V	-6.4A
	100mΩ @ V <sub>GS</sub> = -4.5V	-5.0A

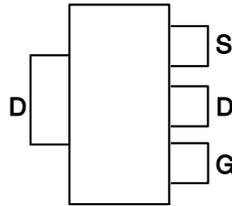
## Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(on)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

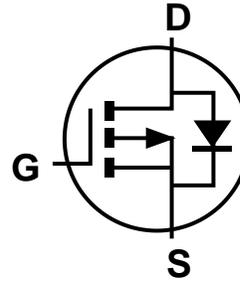
- DC-DC converters
- Power management functions
- Backlighting



Top View



Pin Out - Top



Equivalent Circuit

## Features and Benefits

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>

## Mechanical Data

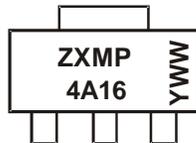
- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Ⓔ3
- Weight: 0.112 grams (Approximate)

## Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
ZXMP4A16GTA	SOT223 (Type DN)	1000	Tape & Reel
ZXMP4A16GTC	SOT223 (Type DN)	4000	Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



ZXMP4A16 = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 2 = 2022)  
 WW or  $\bar{W}W$  = Week Code (01 to 53)

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V <sub>DSS</sub>	-40	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = -10V	I <sub>D</sub>	T <sub>A</sub> = +25°C (Note 5)	-6.4
		T <sub>A</sub> = +70°C (Note 5)	-5.1
		T <sub>A</sub> = +25°C (Note 6)	-4.6
Maximum Body Diode Forward Current (Note 5)	I <sub>S</sub>	-6.4	A
Pulsed Drain Current (Note 7)	I <sub>DM</sub>	-21	A
Pulsed Source Current (Note 7)	I <sub>SM</sub>	-21	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

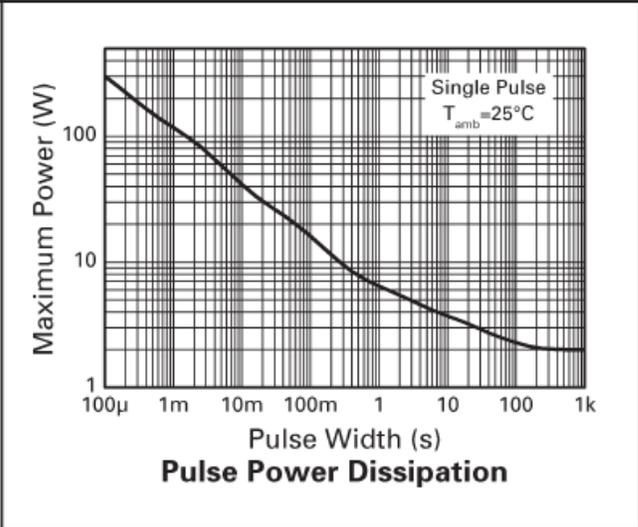
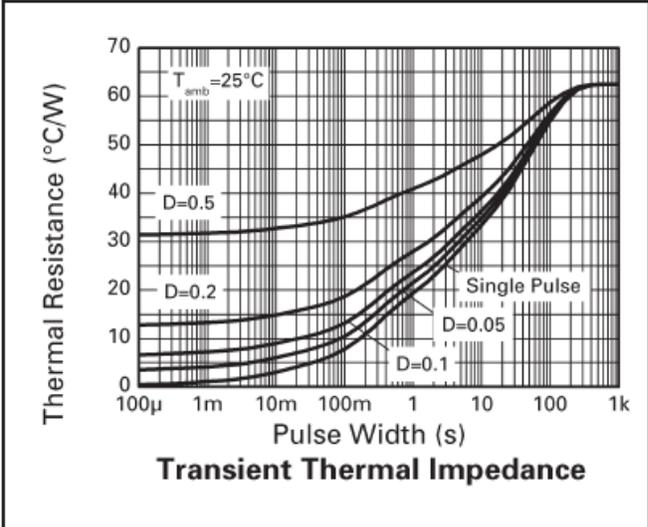
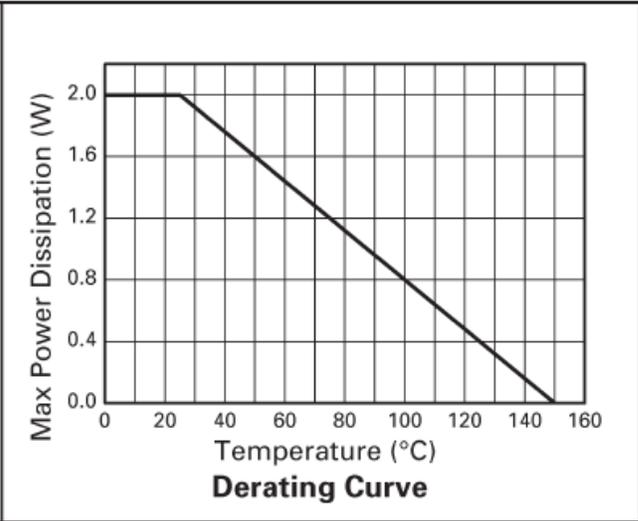
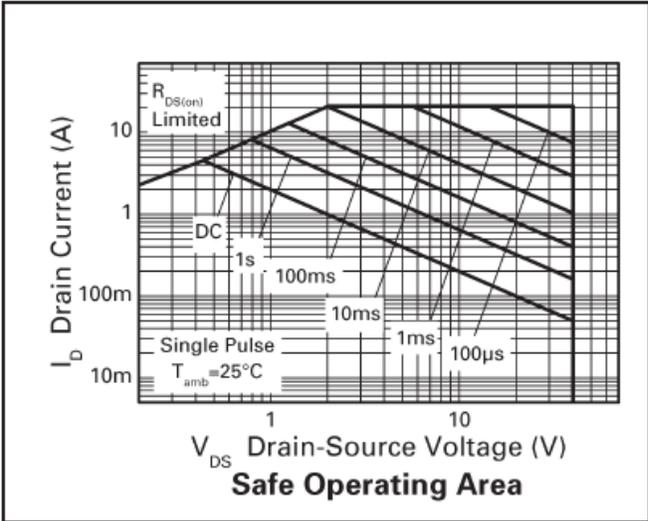
Characteristic	Symbol	Value	Units
Total Power Dissipation Linear Derating Factor	P <sub>D</sub>	T <sub>A</sub> = +25°C (Note 6)	2.0 16
Total Power Dissipation Linear Derating Factor		T <sub>A</sub> = +25°C (Note 5)	3.9 31
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	Steady State (Note 6)	62.5
		Steady State (Note 5)	32
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

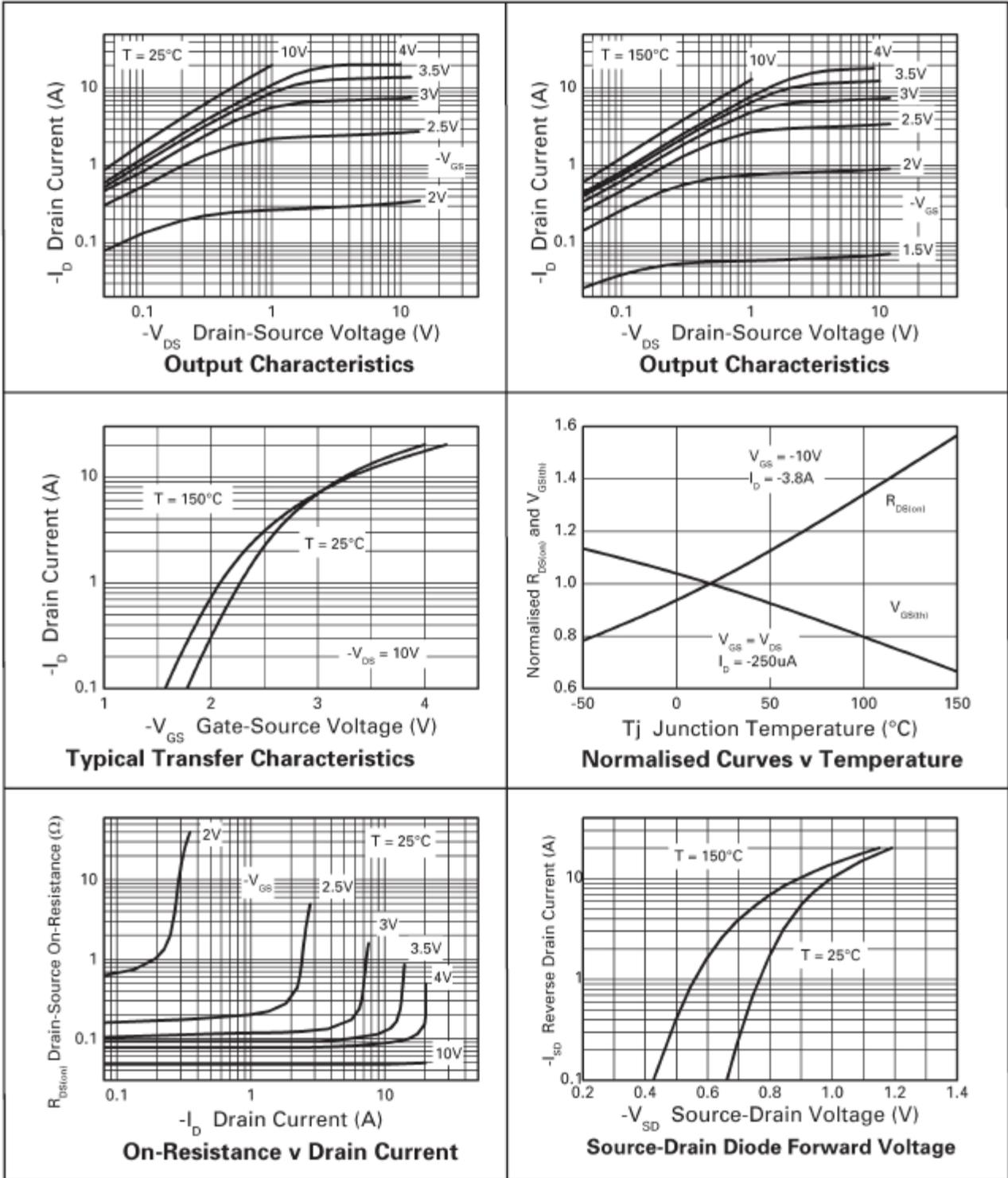
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 8)</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40	—	—	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250μA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	-1.0	μA	V <sub>DS</sub> = -40V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V
<b>ON CHARACTERISTICS (Note 8)</b>						
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.0	—	—	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250μA
Static Drain-Source On-Resistance (Note 9)	R <sub>DS(on)</sub>	—	—	60	mΩ	V <sub>GS</sub> = -10V, I <sub>D</sub> = -3.8A
		—	—	100		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -2.9A
Diode Forward Voltage (Note 9)	V <sub>SD</sub>	—	-0.85	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -3.4A
Forward Transconductance (Notes 9 & 10)	g <sub>fs</sub>	—	8.85	—	S	V <sub>DS</sub> = -15V, I <sub>D</sub> = -3.8A
<b>DYNAMIC CHARACTERISTICS (Note 10)</b>						
Input Capacitance	C <sub>iss</sub>	—	1,007	—	pF	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V f = 1.0MHz
Output Capacitance	C <sub>oss</sub>	—	130	—		
Reverse Transfer Capacitance	C <sub>rss</sub>	—	85	—		
Total Gate Charge (V <sub>GS</sub> = -5.0V)	Q <sub>g</sub>	—	13.6	—	nC	V <sub>DS</sub> = -20V, I <sub>D</sub> = -3.8A
Total Gate Charge (V <sub>GS</sub> = -10V)	Q <sub>g</sub>	—	26.1	—		
Gate-Source Charge	Q <sub>gs</sub>	—	2.8	—		
Gate-Drain Charge	Q <sub>gd</sub>	—	4.8	—		
Turn-On Delay Time	t <sub>D(on)</sub>	—	2.33	—	ns	V <sub>GS</sub> = -10V, V <sub>DD</sub> = -20V, R <sub>G</sub> = 6.0Ω I <sub>D</sub> = -1.0A
Turn-On Rise Time	t <sub>r</sub>	—	8.84	—		
Turn-Off Delay Time	t <sub>D(off)</sub>	—	29.18	—		
Turn-Off Fall Time	t <sub>f</sub>	—	12.54	—		
Body Diode Reverse Recovery Time	t <sub>rr</sub>	—	27.2	—	ns	I <sub>F</sub> = -3A, dI/dt = 100A/μs
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	—	25.4	—	nC	

- Notes:
- For a device surface mounted on FR4 PCB measured at t ≤ 10s.
  - For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
  - Repetitive rating 25mm x 25mm FR4 PCB, D = 0.05, pulse width limited by maximum junction temperature.
  - Short duration pulse test used to minimize self-heating effect.
  - Measured under pulsed conditions. Width ≤ 300μs. Duty cycle ≤ 2%.
  - Guaranteed by design. Not subject to product testing.

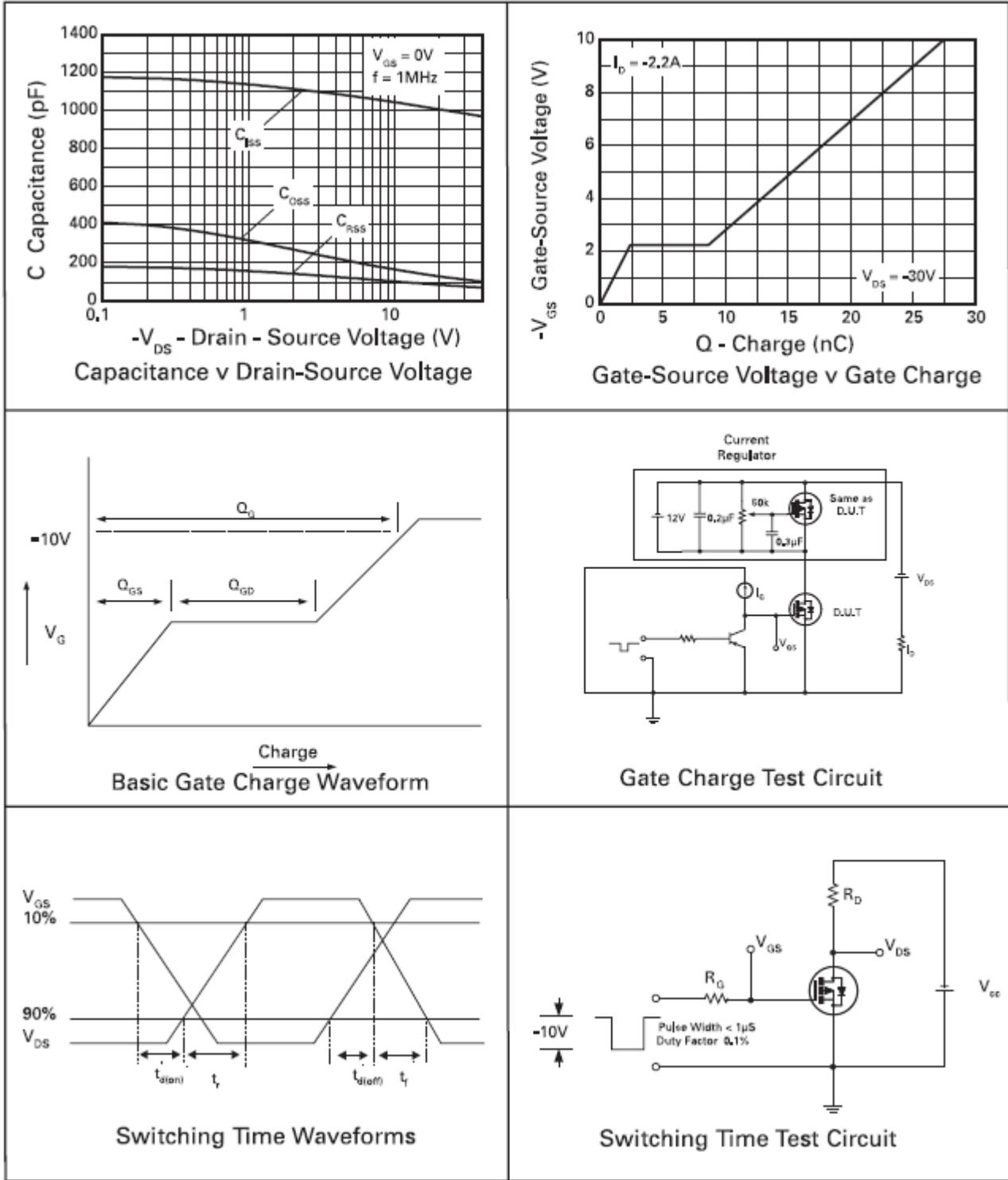
**Typical Characteristics**



**Typical Characteristics** (continued)



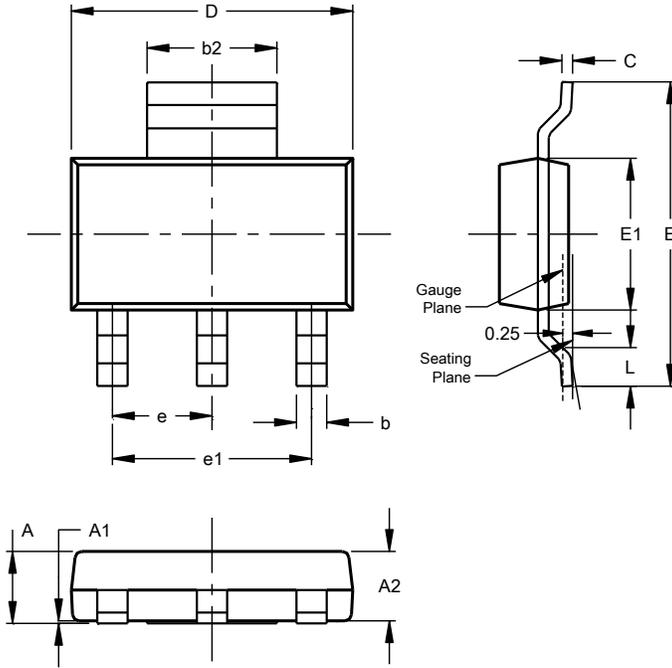
**Typical Characteristics** (continued)



**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT223 (Type DN)**

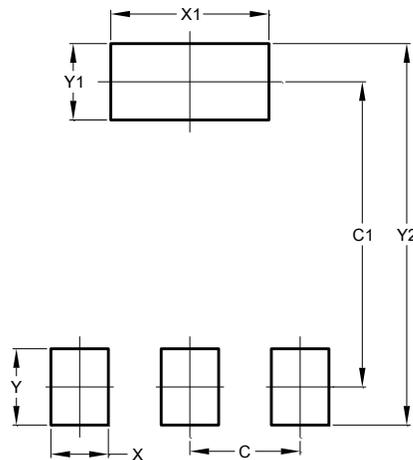


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT223 (Type DN)**



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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